2N7002KTB

60V N-Channel Enhancement Mode MOSFET - ESD Protected

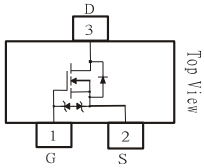
FEATURES

- $R_{DS(ON)}$, V_{GS}@10V,I_{DS}@500mA=3Ω
- $R_{DS(ON)}$, V_{GS}@4.5V,I_{DS}@200mA=4Ω

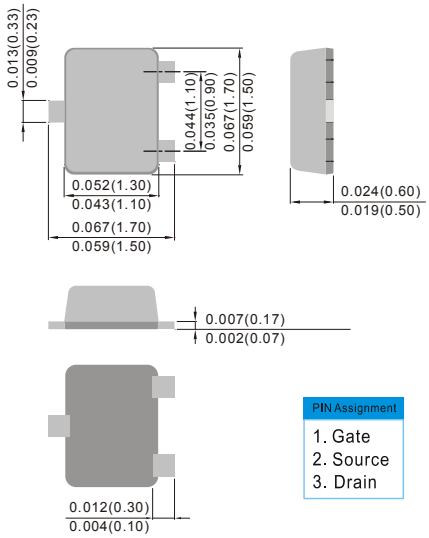
- Advanced Trench Process Technology
- High Density Cell Design For Ultra Low On-Resistance
- Very Low Leakage Current In Off Condition
- Specially Designed for Battery Operated Systems, Solid-State Relays Drivers : Relays, Displays, Lamps, Solenoids, Memories, etc.
- ESD Protected 2KV HBM
- Lead free in comply with EU RoHS 2002/95/EC directives.
- Green molding compound as per IEC61249 Std. . (Halogen Free)

MECHANICAL DATA

- Case: SOT-523 Package
- Terminals : Solderable per MIL-STD-750,Method 2026
- Approx. Weight: 0.00007 ounces, 0.002 grams
- Marking : 27



SOT-523 Unit : inch(mm)



Maximum RATINGS and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	Symbol	Limit	Units
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D	115	mA
Pulsed Drain Current [1]	I_{DM}	800	mA
Maximum Power Dissipation T_A=25°C T_A=75°C	P_D	200 150	mW
Operating Junction and Storage Temperature Range	T_J,T_{STG}	-55 to + 150	°C
Junction-to Ambient Thermal Resistance(PCB mounted)[2]	$R_{\theta JA}$	883	°C/W

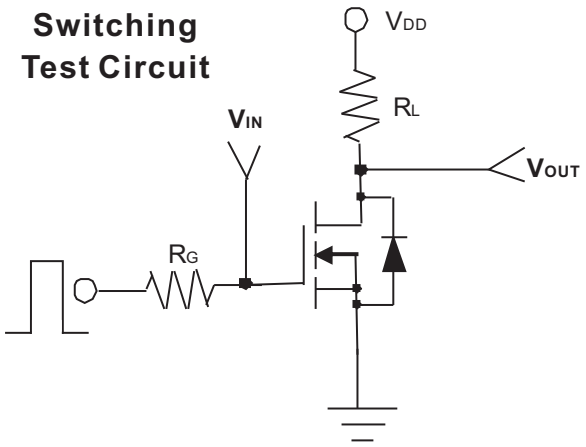
Note: 1. Maximum DC current limited by the package
2. Surface mounted on FR4 board, t ≤ 5 sec

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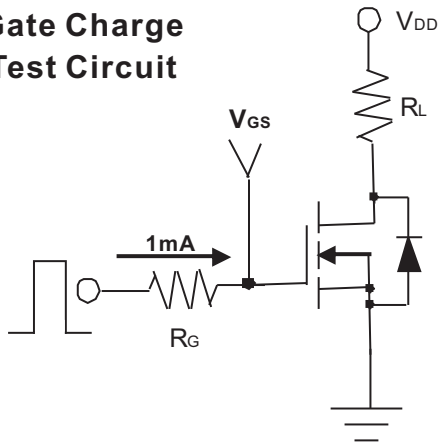
ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Units
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=10μA	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=250μA	1	-	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS}=4.5V, I_D=200mA	-	-	4.0	Ω
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS}=10V, I_D=500mA	-	-	3.0	
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=60V, V_{GS}=0V	-	-	1	μA
Gate Body Leakage	I_{GSS}	V_{GS}=±20V, V_{DS}=0V	-	-	±10	μA
Forward Transconductance	g_{fS}	V_{DS}=15V, I_D=250mA	100	-	-	mS
Dynamic						
Total Gate Charge	Q_g	V_{DS}=15V, I_D=200mA V_{GS}=4.5V	-	-	0.8	nC
Turn-On Delay Time	$td_{(on)}$	V_{DD}=30V , R_L=150Ω I_D=200mA , V_{GEN}=10V R_G=10Ω	-	-	20	ns
Turn-Off Delay Time	$td_{(off)}$		-	-	125	
Input Capacitance	C_{iss}	V_{DS}=25V, V_{GS}=0V f=1.0MHz	-	-	35	pF
Output Capacitance	C_{oss}		-	-	10	
Reverse Transfer Capacitance	C_{rss}		-	-	5	
Source-Drain Diode						
Diode Forward Voltage	V_{SD}	I_S=200mA , V_{GS}=0V	-	0.82	1.3	V
Continuous Diode Forward Current	I_s	-	-	-	115	mA
Pulsed Diode Forward Current	I_{sM}	-	-	-	800	mA

Switching Test Circuit



Gate Charge Test Circuit



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Typical Characteristics Curves (T_A=25°C,unless otherwise noted)

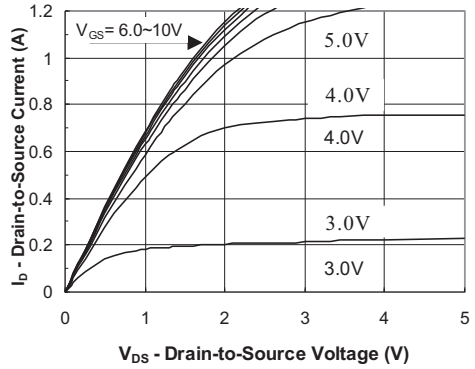


FIG.1- Output Characteristic

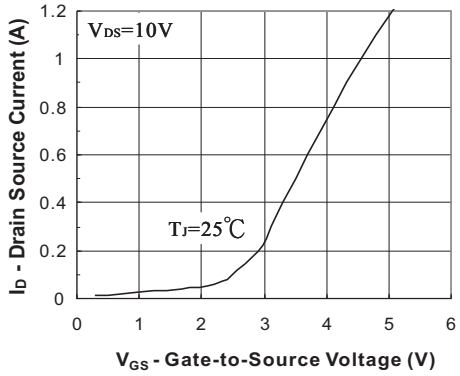


FIG.2- Transfer Characteristic

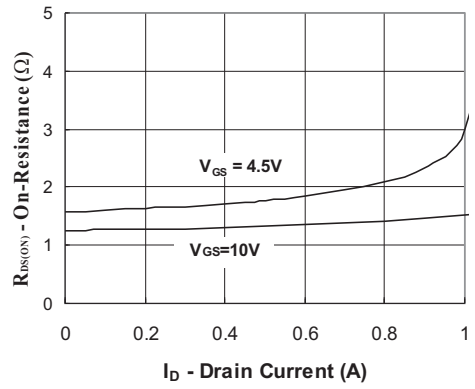


FIG.3- On Resistance vs Drain Current

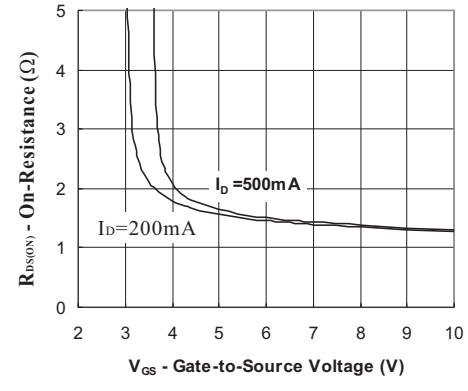


FIG.4- On Resistance vs Gate to Source Voltage

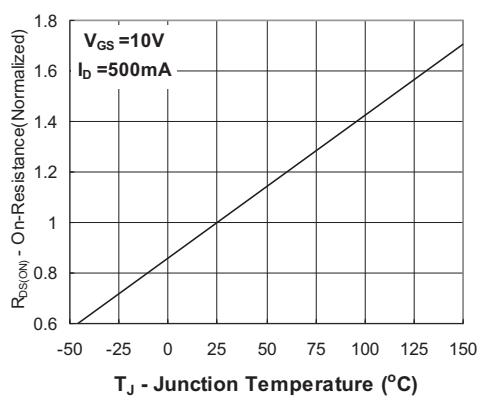


FIG.5- On Resistance vs Junction Temperature

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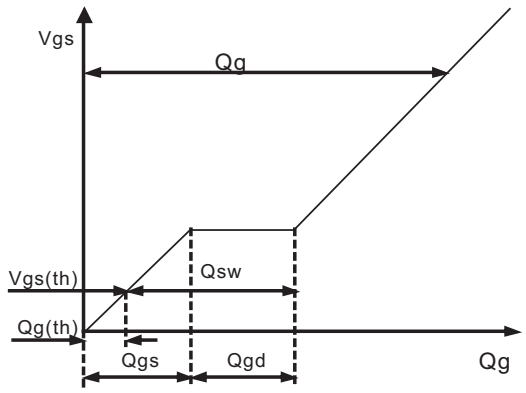


Fig.6 - Gate Charge Waveform

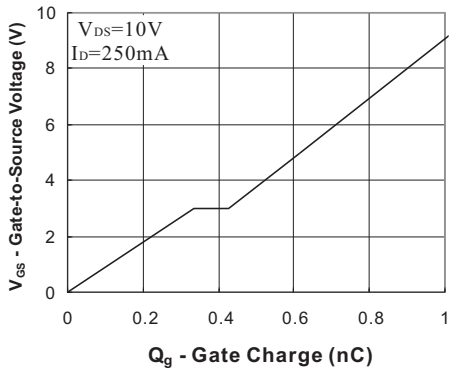


Fig.7 - Gate Charge

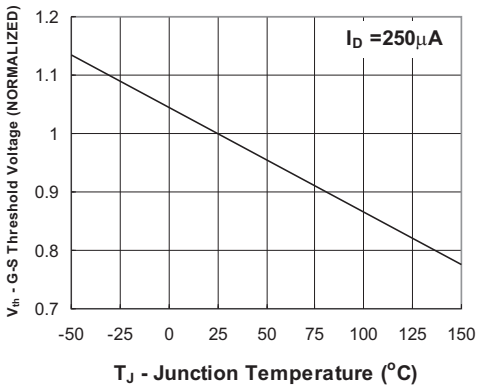


Fig.8 - Threshold Voltage vs Temperature

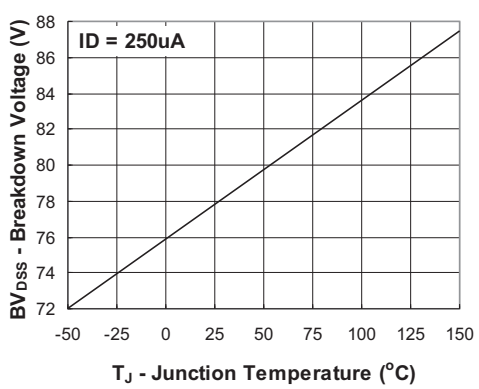


Fig.9 - Breakdown Voltage vs Junction Temperature

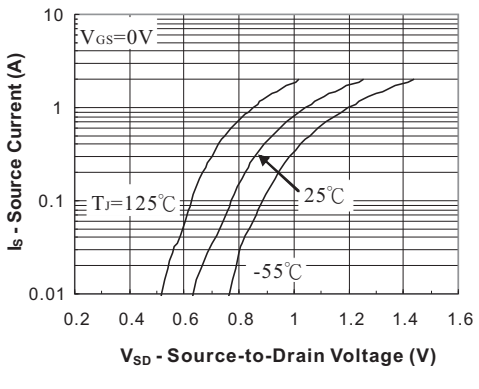
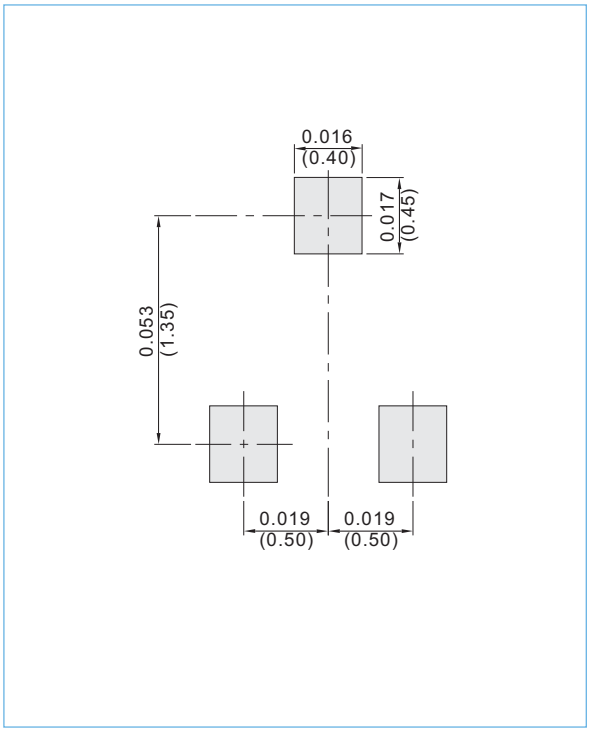


Fig.10 - Source-Drain Diode Forward Voltage

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MOUNTING PAD LAYOUT

SOT-523 Unit : inch(mm)



ORDER INFORMATION

- Packing information

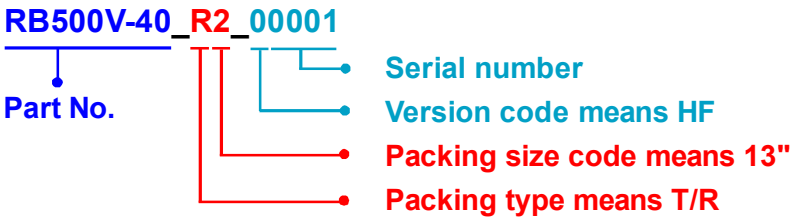
  T/R - 4K per 7" plastic Reel

2N7002KTB

Part No_packing code_Version

2N7002KTB_R1_00001

For example :



Packing Code XX				Version Code XXXXX		
Packing type	1st Code	Packing size code	2nd Code	HF or RoHS	1st Code	2nd~5th Code
Tape and Ammunition Box (T/B)	A	N/A	0	HF	0	serial number
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number
Bulk Packing (B/P)	B	13"	2			
Tube Packing (T/P)	T	26mm	X			
Tape and Reel (Right Oriented) (TRR)	S	52mm	Y			
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U			
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D			

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